NSN 5961-00-403-2585

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-403-2585 **Inclosure Material:** Metal **Overall Length:** Between 0.115 inches and 0.150 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-52 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 45.0 collector to base voltage/static/emitter open all transistor and 45.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Internal junction configutation transistor pnp **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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